

## **Excellent Integrated System Limited**

Stocking Distributor

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CEL (California Eastern Laboratories) NE681M03-A

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**Distributor of CEL (California Eastern Laboratories): Excellent Integrated System Limited** Datasheet of NE681M03-A - TRANSISTOR NPN 1GHZ M03 Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

# CEL NEC'S NPN SILICON TRANSISTOR

NE681M03

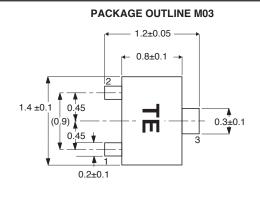
#### **FEATURES**

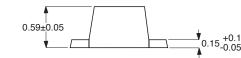
- NEW M03 PACKAGE:
  - · Smallest transistor outline package available
  - Low profile/0.59 mm package height
  - Flat lead style for better RF performance
- HIGH GAIN BANDWIDTH PRODUCT: ft = 7 GHz
- LOW NOISE FIGURE:
  - NF = 1.4 dB

DESCRIPTION

package styles.

#### OUTLINE DIMENSIONS (Units in mm)





**PIN CONNECTIONS** 

- 1. Emitter
- 2. Base
- 3. Collector

#### ELECTRICAL CHARACTERISTICS (TA = 25°C)

NEC's NE681M03 transistor is ideal for low noise, high gain,

and low cost amplifier applications. NEC's new low profile/

flat lead style "M03" package is ideal for today's portable wireless applications. The NE681 is also available in chip,

Micro-x, and six different low cost plastic surface mount

| PART NUMBER<br>EIAJ <sup>1</sup> REGISTERED NUMBER<br>PACKAGE OUTLINE |   |       | NE681M03<br>2SC5433<br>M03 |     |     |
|---|---|-------|----------------------------|-----|-----|
| SYMBOLS   | PARAMETERS AND CONDITIONS                               | UNITS | MIN                        | ТҮР | МАХ |
| fт  | Gain Bandwidth at VCE = 3 V, IC = 7 mA, f = 1 GHz       | GHz   | 4.5                        | 7.0 |     |
| NF  | Noise Figure at VCE = 3 V, IC = 7 mA, f = 1 GHz         | dB    |                            | 1.4 | 2.7 |
| IS21El <sup>2</sup>   | Insertion Power Gain at VCE = 3 V, IC = 7 mA, f = 1 GHz | dB    | 10                         | 12  |     |
| hfe <sup>2</sup>  | Forward Current Gain at VCE = 3 V, IC = 7 mA            |       | 80                         |     | 145 |
| Ісво  | Collector Cutoff Current at VcB = 10 V, IE = 0          | μΑ    |                            |     | 0.8 |
| Іево  | Emitter Cutoff Current at VEB = 1 V, IC = 0             | μΑ    |                            |     | 0.8 |
| CRE <sup>3</sup>  | Feedback Capacitance at VcB = 3 V, IE = 0, f = 1 MHz    | pF    |                            |     | 0.9 |

Notes:

1. Electronic Industrial Association of Japan.

2. Pulsed measurement, pulse width < 350  $\mu s,$  duty cycle < 2 %.

3. Capacitance is measured with emitter and case connected to the guard terminal at the bridge.



NE681M03

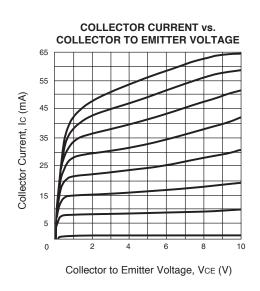
#### ABSOLUTE MAXIMUM RATINGS<sup>1</sup> (TA = 25°C)

| SYMBOLS | PARAMETERS                   | UNITS | RATINGS     |
|---------|------------------------------|-------|-------------|
| Vсво    | Collector to Base Voltage    | V     | 20          |
| VCEO    | Collector to Emitter Voltage | V     | 10          |
| VEBO    | Emitter to Base Voltage      | V     | 1.5         |
| Ic      | Collector Current            | mA    | 65          |
| Рт      | Total Power Dissipation      | mW    | 125         |
| TJ      | Junction Temperature         | °C    | 150         |
| Тѕтс    | Storage Temperature          | °C    | -65 to +150 |

Note:

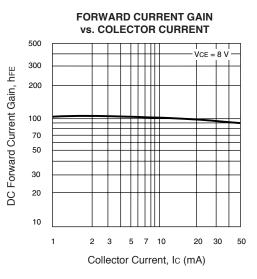
1. Operation in excess of any one of these parameters may result in permanent damage.

### TYPICAL PERFORMANCE CURVES (TA = 25°C)



#### **ORDERING INFORMATION**

| PART NUMBER   | QUANTITY |
|---------------|----------|
| NE681M03-A    |          |
| NE681M03-T1-A |          |

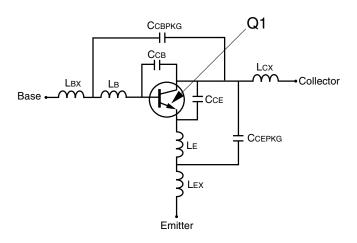




**SCHEMATIC** 

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#### NE681M03



### **BJT NONLINEAR MODEL PARAMETERS** <sup>(1)</sup>

| Parameters | Q1        | Parameters | Q1     |
|------------|-----------|------------|--------|
| IS         | 239.6e-18 | MJC        | 0.223  |
| BF         | 125       | XCJC       | 0      |
| NF         | 0.9854    | CJS        | 0      |
| VAF        | 12        | VJS        | 0.75   |
| IKF        | 0.200     | MJS        | 0      |
| ISE        | 1.933e-6  | FC         | 0.5    |
| NE         | 50        | TF         | 10e-12 |
| BR         | 18.25     | XTF        | 25     |
| NR         | 0.9771    | VTF        | 0.40   |
| VAR        | 10        | ITF        | 0.13   |
| IKR        | 11.81e-3  | PTF        | 43.1   |
| ISC        | 1.55e-18  | TR         | 0.3e-9 |
| NC         | 1.860     | EG         | 1.11   |
| RE         | 0.870     | XTB        | 0      |
| RB         | 4.0       | XTI        | 3      |
| RBM        | 5.2       | KF         | 0      |
| IRB        | 1e-6      | AF         | 1      |
| RC         | 4.635     |            |        |
| CJE        | 1.2e-12   |            |        |
| VJE        | 0.77      |            |        |
| MJE        | 0.4844    |            |        |
| CJC        | 0.4e-12   |            |        |
| VJC        | 0.5275    |            |        |

#### UNITS

| Parameter   | Units   |
|-------------|---------|
| time        | seconds |
| capacitance | farads  |
| inductance  | henries |
| resistance  | ohms    |
| voltage     | volts   |
| current     | amps    |

#### **ADDITIONAL PARAMETERS**

| Parameters | 681M03   |  |
|------------|----------|--|
| Ссв        | 0.07e-12 |  |
| CCE        | 0.01e-12 |  |
| Lв         | 0.3e-9   |  |
| LE         | 0.8e-9   |  |
| Ссвркд     | 0.08e-12 |  |
| Ссеркд     | 0.08e-12 |  |
| LBX        | 0.12e-9  |  |
| Lcx        | 0.10e-9  |  |
| Lex        | 0.12e-9  |  |

MODEL RANGE

 Frequency:
 0.1 to 5.0 GHz

 Bias:
 VcE = 2.5 V to 8 V, Ic = 0.3 mA to 20 mA

 Date:
 12/98

 hFE = 124 at VcE = 3 V, Ic = 7 mA

(1) Gummel-Poon Model

Life Support Applications

These NEC products are not intended for use in life support devices, appliances, or systems where the malfunction of these products can reasonably be expected to result in personal injury. The customers of CEL using or selling these products for use in such applications do so at their own risk and agree to fully indemnify CEL for all damages resulting from such improper use or sale.

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06/10/2002





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Subject: Compliance with EU Directives

CEL certifies, to its knowledge, that semiconductor and laser products detailed below are compliant with the requirements of European Union (EU) Directive 2002/95/EC Restriction on Use of Hazardous Substances in electrical and electronic equipment (RoHS) and the requirements of EU Directive 2003/11/EC Restriction on Penta and Octa BDE.

CEL Pb-free products have the same base part number with a suffix added. The suffix –A indicates that the device is Pb-free. The –AZ suffix is used to designate devices containing Pb which are exempted from the requirement of RoHS directive (\*). In all cases the devices have Pb-free terminals. All devices with these suffixes meet the requirements of the RoHS directive.

This status is based on CEL's understanding of the EU Directives and knowledge of the materials that go into its products as of the date of disclosure of this information.

| Restricted Substance<br>per RoHS | Concentration Limit per RoHS<br>(values are not yet fixed) | Concentration contained<br>in CEL devices |            |
|----------------------------------|--|---|------------|
| Lead (Pb)                        | < 1000 PPM   | -A<br>Not Detected                        | -AZ<br>(*) |
| Mercury                          | < 1000 PPM   | Not Detected                              |            |
| Cadmium                          | < 100 PPM  | Not Detected                              |            |
| Hexavalent Chromium              | < 1000 PPM   | Not Detected                              |            |
| РВВ                              | < 1000 PPM   | Not Detected                              |            |
| PBDE                             | < 1000 PPM   | Not Detected                              |            |

If you should have any additional questions regarding our devices and compliance to environmental standards, please do not hesitate to contact your local representative.

See CEL Terms and Conditions for additional clarification of warranties and liability.

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